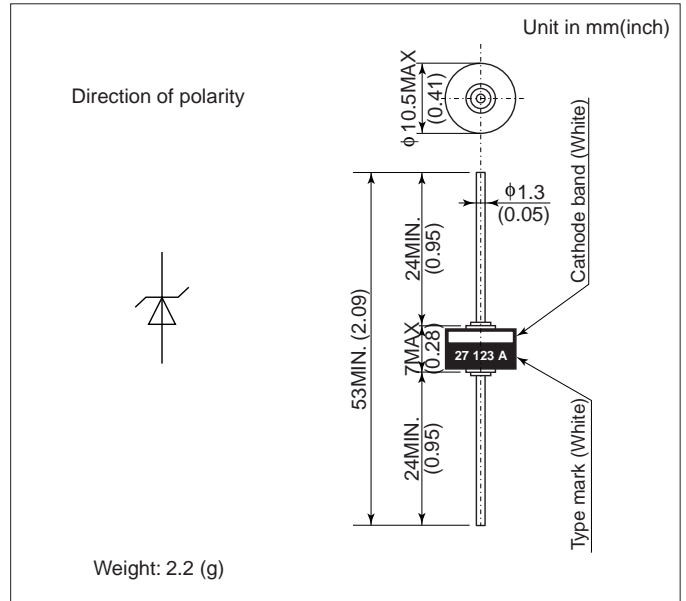


ZSA5A27

FEATURES

- High transient reverse power capability suitable for protecting automobile electronic components etc.
- Axial lead type easy mounting on PC board.

OUTLINE DRAWING



ABSOLUTE MAXIMUM RATINGS

Items	Symbols	Units	Ratings
Non-Repetitive Peak Reverse One-Cycle Dissipation	P_{RSM}	W	3,000(Rectangular pulse $t=1ms$ $T_j=25^\circ C$ start)
Non-Repetitive Peak Reverse Surge Current	I_{RSM}	A	62(Time constant=14.5ms, $L=10mm$, $T_L=25^\circ C$)
DC Reverse Voltage	V_{DC}	V	18
Operating Junction Temperature	T_j	$^\circ C$	-40 ~ +150
Storage Temperature	T_{stg}	$^\circ C$	-40 ~ +150

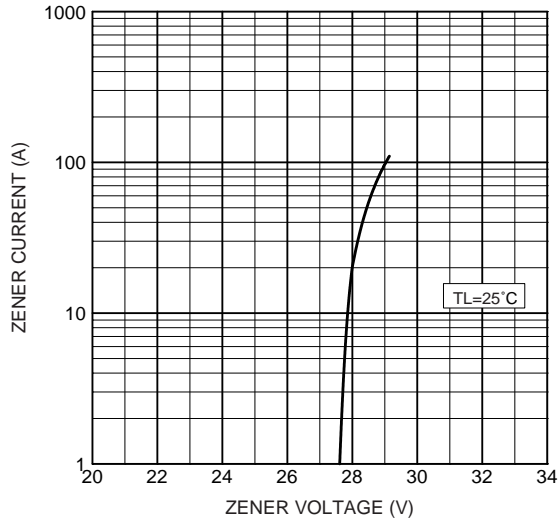
- Notes (1) Lead mounting : Lead temperature $300^\circ C$ max. to 10mm from body for 5sec. max..
 (2) Mechanical strength : Bending $90^\circ \times 2$ cycles or $180^\circ \times 1$ cycle, Tensile 3kg, Twist $90^\circ \times 1$ cycle.

CHARACTERISTICS($T_L=25^\circ C$)

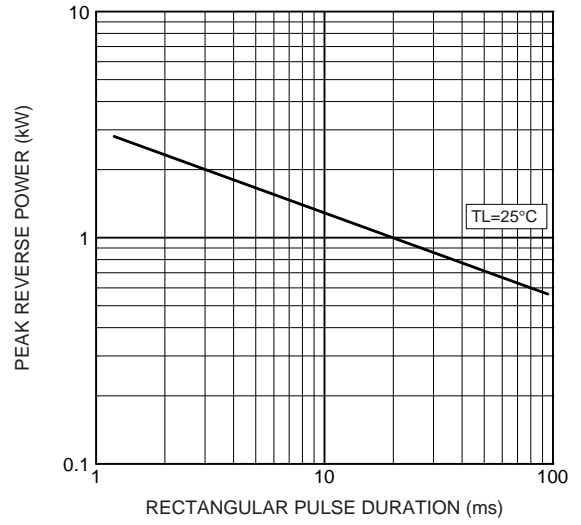
Items	Symbols	Units	Min.	Typ.	Max.	Test Conditions
Zener Voltage	V_Z	V	24	27	30	$I_Z=10mA$
Dynamic Impedance	Z_Z	Ω	-	-	50	$I_Z=10mA$
Zener Voltage Temperature Coefficient	γ_Z	$\%/^\circ C$	-	0.074	-	$I_Z=10mA$
Peak Forward Voltage	V_{FM}	V	-	-	2	$I_{FM}=6A$
Peak Reverse Current	I_{RRM}	μA	-	-	50	$V_R=18V$

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Typical zener characteristics



Typical reverse power characteristic
(Rectangular pulse non-repetitive)



HITACHI POWER SEMICONDUCTORS

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